

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHC240F,TC74VHC240FW,TC74VHC240FT,TC74VHC240FK TC74VHC244F,TC74VHC244FW,TC74VHC244FT,TC74VHC244FK

Octal Bus Buffer

TC74VHC240F/FW/FT/FK

Inverted, 3-State Outputs

TC74VHC244F/FW/FT/FK

Non-Inverted, 3-State Outputs

The TC74VHC240 and 244 are advanced high speed CMOS OCTAL BUS BUFFERS fabricated with silicon gate C²MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The 74VHC240 is an inverting 3-state buffer having two active-low output enables. The TC74VHC244 is a non-inverting 3-state buffer, and has two active-low output enables.

These devices are designed to be used with 3-state memory address drivers, etc.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

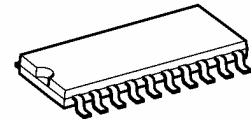
- High speed: $t_{pd} = 3.9 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu\text{A (max)}$ at $T_a = 25^\circ\text{C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC} \text{ (min)}$
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: $V_{CC} \text{ (opr)} = 2 \text{ to } 5.5 \text{ V}$
- Low noise: $V_{OLP} = 0.9 \text{ V (max)}$
- Pin and function compatible with 74ALS240/244

Weight

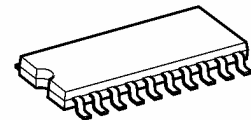
SOP20-P-300-1.27A	: 0.22 g (typ.)
SOP20-P-300-1.27	: 0.22 g (typ.)
SOL20-P-300-1.27	: 0.46 g (typ.)
TSSOP20-P-0044-0.65A	: 0.08 g (typ.)
VSSOP20-P-0030-0.50	: 0.03 g (typ.)

Note: xxxFW (JEDEC SOP) is not available in Japan.

TC74VHC240F, TC74VHC244F

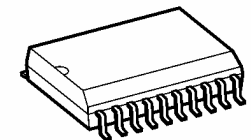


SOP20-P-300-1.27A



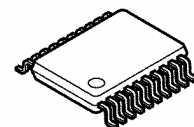
SOP20-P-300-1.27

TC74VHC240FW, TC74VHC244FW



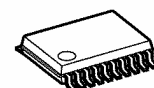
SOL20-P-300-1.27

TC74VHC240FT, TC74VHC244FT



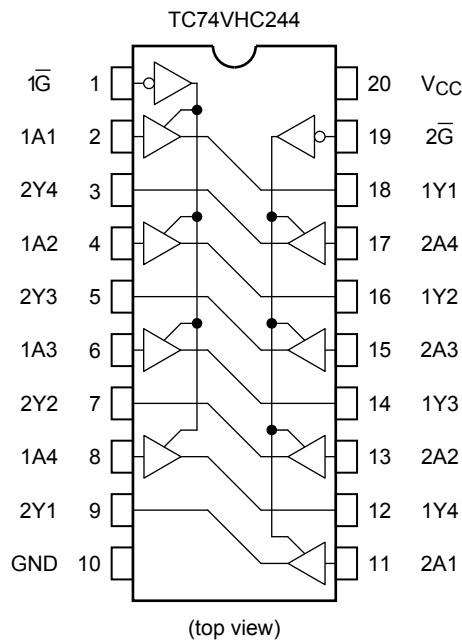
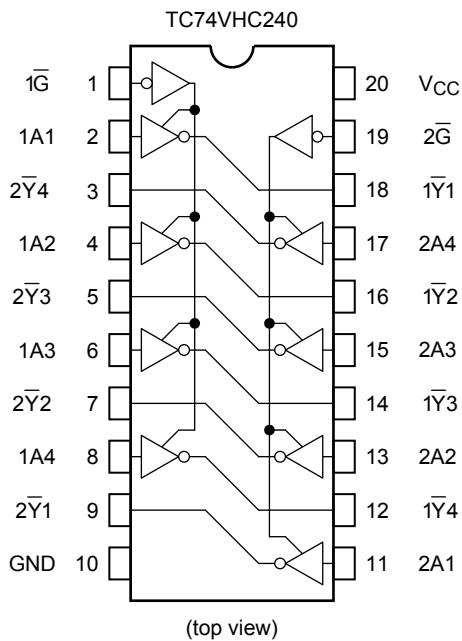
TSSOP20-P-0044-0.65A

TC74VHC240FK, TC74VHC244FK

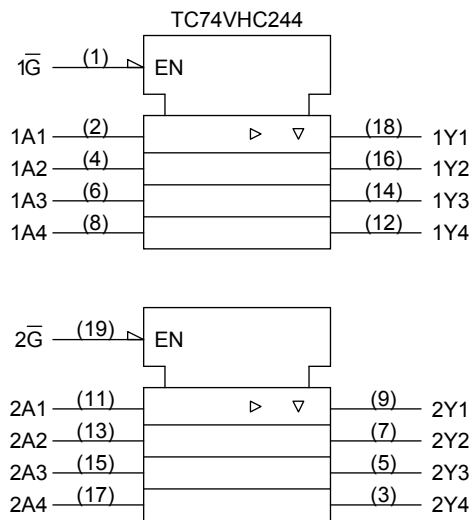
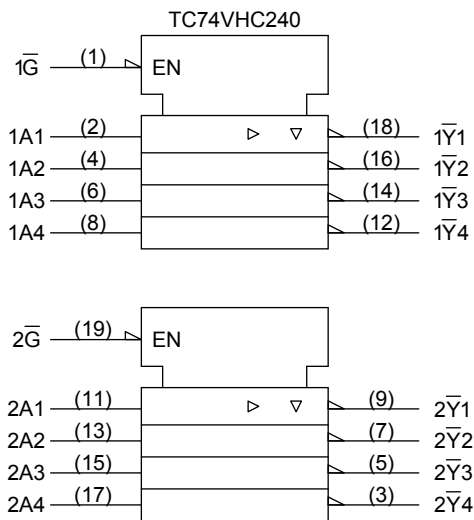


VSSOP20-P-0030-0.50

Pin Assignment



Logic Symbol



Truth Table

Inputs		Outputs	
$\overline{G}$	A_n	Y_n	$\overline{Y}_n$
L	L	L	H
L	H	H	L
H	X	Z	Z

X: Don't care

Z: High impedance

Y_n : TC74VHC244

$\overline{Y}_n$: TC74VHC240

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
DC input voltage	V_{IN}	-0.5 to 7.0	V
DC output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	-20	mA
Output diode current	I_{OK}	± 20	mA
DC output current	I_{OUT}	± 25	mA
DC V_{CC} /ground current	I_{CC}	± 75	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 ($V_{CC} = 3.3 \pm 0.3$ V) 0 to 20 ($V_{CC} = 5 \pm 0.5$ V)	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Electrical Characteristics
DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
				V _{CC} (V)	Min	Typ.	Max	Min		Max
High-level input voltage	V _{IH}	—		2.0 3.0 to 5.5	1.50 V _{CC} × 0.7	— —	— —	1.50 V _{CC} × 0.7	— —	V
Low-level input voltage	V _{IL}	—		2.0 3.0 to 5.5	— —	— —	0.50 V _{CC} × 0.3	— —	0.50 V _{CC} × 0.3	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			I _{OH} = -4 mA	3.0	2.58	—	—	2.48	—	
I _{OH} = -8 mA	4.5	3.94		—	—	3.80	—			
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
				4.5	—	0.0	0.1	—	0.1	
			I _{OL} = 4 mA	3.0	—	—	0.36	—	0.44	
				I _{OL} = 8 mA	4.5	—	—	0.36	—	
3-state output off-state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5	—	—	±0.25	—	±2.50	μA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	—	—	4.0	—	40.0	μA

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
			V _{CC} (V)	C _L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time (TC74VHC240)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	5.3	7.5	1.0	9.0	ns
				50	—	7.8	11.0	1.0	12.5	
			5.0 ± 0.5	15	—	3.6	5.5	1.0	6.5	
				50	—	5.1	7.5	1.0	8.5	
Propagation delay time (TC74VHC244)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	5.8	8.4	1.0	10.0	ns
				50	—	8.3	11.9	1.0	13.5	
			5.0 ± 0.5	15	—	3.9	5.5	1.0	6.5	
				50	—	5.4	7.5	1.0	8.5	
3-state output enable time	t_{pZL} t_{pZH}	R _L = 1 kΩ	3.3 ± 0.3	15	—	6.6	10.6	1.0	12.5	ns
				50	—	9.1	14.1	1.0	16.0	
			5.0 ± 0.5	15	—	4.7	7.3	1.0	8.5	
				50	—	6.2	9.3	1.0	10.5	
3-state output disable time	t_{pLZ} t_{pHZ}	R _L = 1 kΩ	3.3 ± 0.3	50	—	10.3	14.0	1.0	16.0	ns
			5.0 ± 0.5	50	—	6.7	9.2	1.0	10.5	
Output to output skew	t_{oSLH} t_{oSHL}	(Note 1)	3.3 ± 0.3	50	—	—	1.5	—	1.5	ns
			5.0 ± 0.5	50	—	—	1.0	—	1.0	
Input capacitance	C _{IN}	—			—	4	10	—	10	pF
Output capacitance	C _{OUT}	—			—	6	—	—	—	pF
Power dissipation capacitance (Note 2)	C _{PD}	TC74VHC240			—	17	—	—	—	pF
		TC74VHC244			—	19	—	—	—	

Note 1: Parameter guaranteed by design.

$$t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|$$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

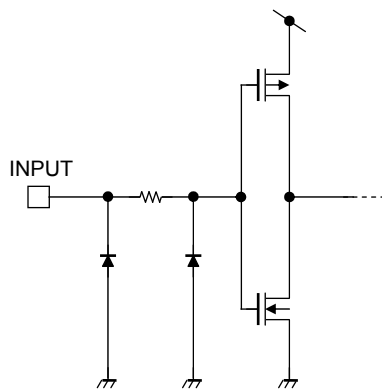
$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$$

Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$) (Note)

Characteristics	Symbol	Test Condition	Ta = 25°C		Unit	
			V _{CC} (V)	Typ. Limit		
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.5 (0.6)	0.8 (0.9)	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	−0.5 (−0.6)	−0.8 (−0.9)	V
Minimum high level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	—	3.5	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	—	1.5	V

Note: The value in () only applies to JEDEC SOP (FW) devices.

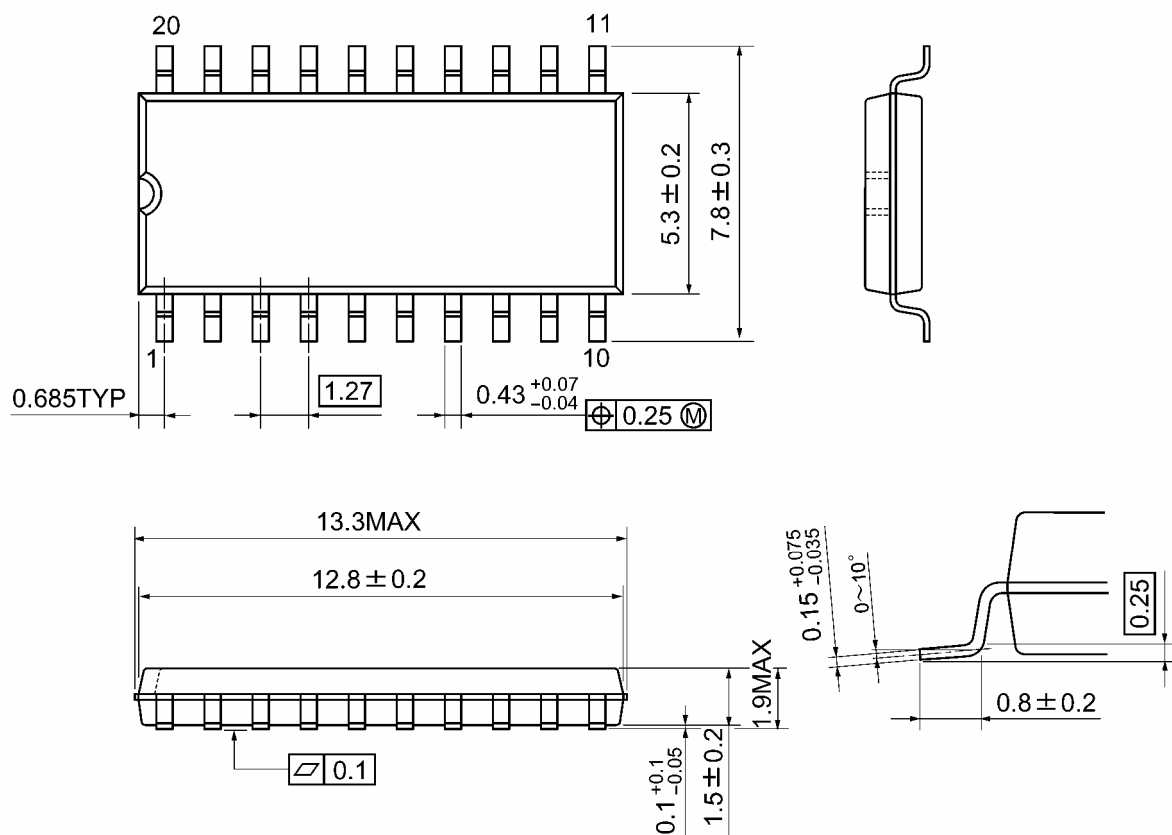
Input Equivalent Circuit



Package Dimensions

SOP20-P-300-1.27A

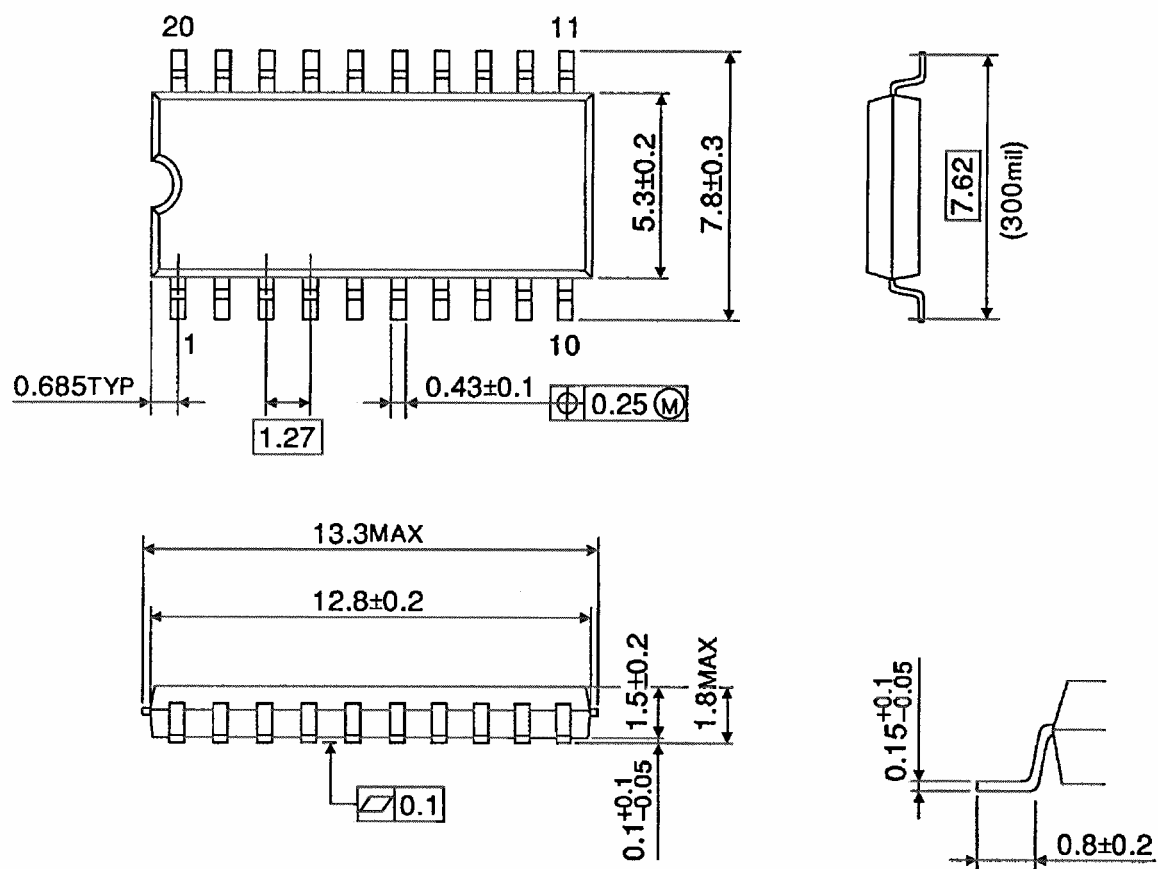
Unit: mm



Weight: 0.22 g (typ.)

SOP20-P-300-1.27

Unit : mm

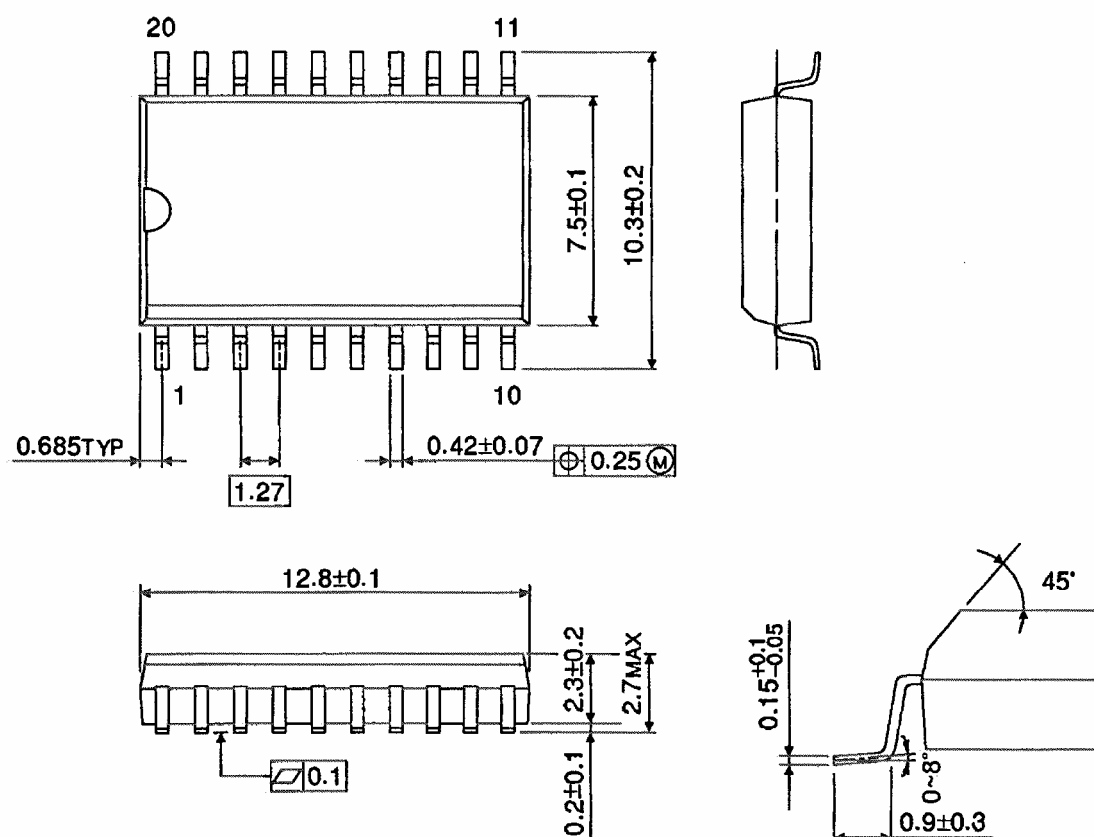


Weight: 0.22 g (typ.)

Package Dimensions (Note)

SOL20-P-300-1.27

Unit : mm



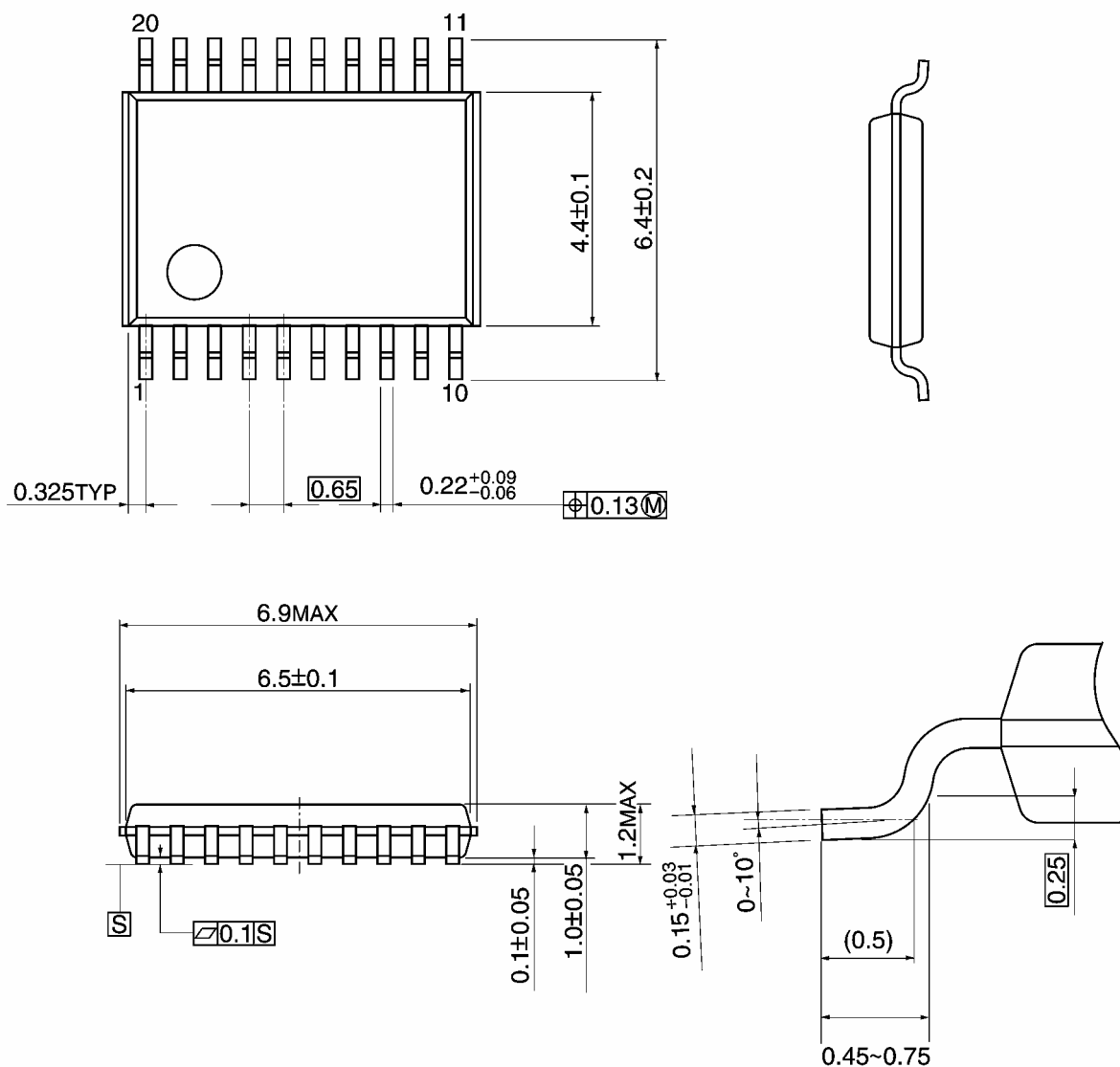
Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

Package Dimensions

TSSOP20-P-0044-0.65A

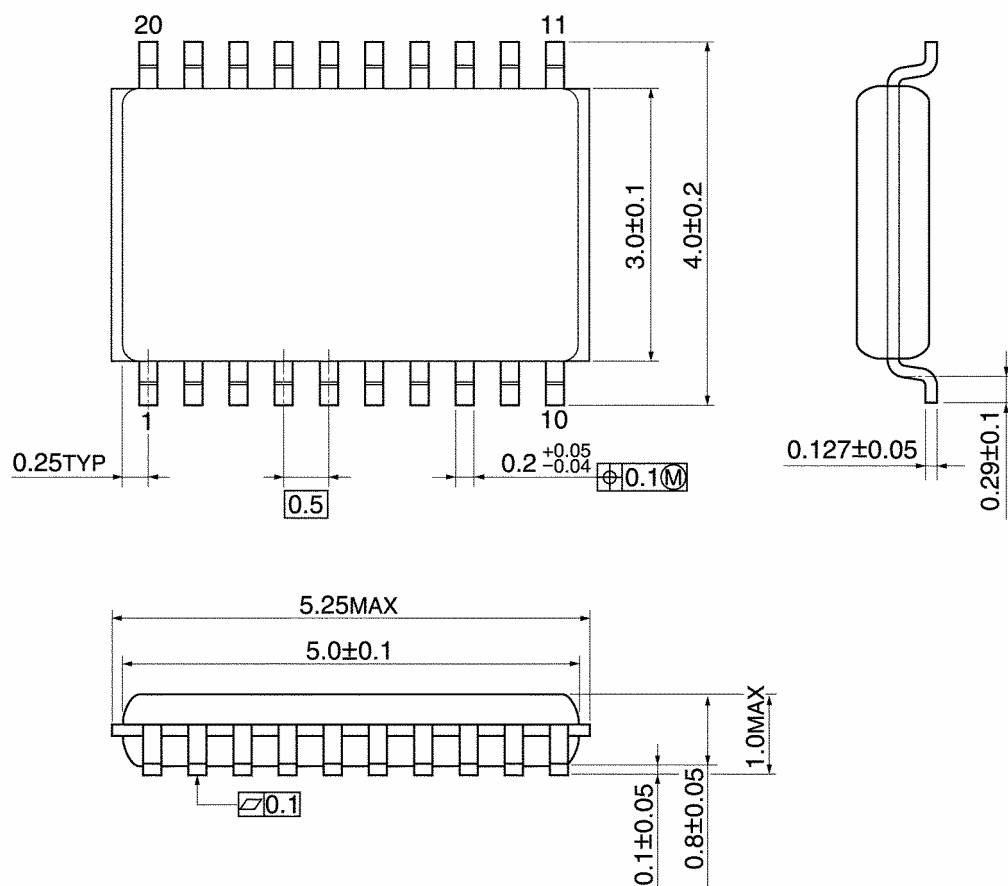
Unit: mm



Weight: 0.08 g (typ.)

VSSOP20-P-0030-0.50

Unit: mm



Weight: 0.03 g (typ.)

Note: Lead (Pb)-Free Packages**SOP20-P-300-1.27A TSSOP20-P-0044-0.65A VSSOP20-P-0030-0.50****RESTRICTIONS ON PRODUCT USE**

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